

# Silicon Bipolar MMIC 1.5 GHz Variable Gain Amplifier

# **Technical Data**

#### IVA-05208

#### **Features**

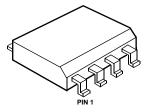
- Differential Input and Output Capability
- DC to 1.5 GHz Bandwidth; 2.0 Gb/s Data Rates
- High Gain: 30 dB Typical
- Wide Gain Control Range: 30 dB Typical
- 5 V Bias
- + 5 V  $V_{gc}$  Control Voltage,  $I_{gc} < 3 \ mA$
- Fast Gain Control Response: < 10 ns Typical
- Low Cost Plastic Surface Mount Package

#### **Description**

The IVA-05208 is a variable gain amplifier housed in a miniature low cost plastic surface mount package. This device can be used in any combination of singleended or differential inputs or outputs (see Functional Block Diagram). The lowest frequency of operation is limited only by the values of user selected blocking and bypass capacitors.

Typical applications include variable gain amplification for fiber optic systems (e.g., SONET) with data rates up to 2.0 Gb/s, mobile radio and satellite receivers, millimeter wave receiver IF amplifiers and communication receivers.

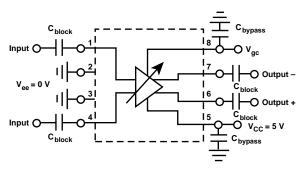
#### **SO-8 Package**



The IVA series of variable gain amplifiers is fabricated using Agilent's 10 GHz  $f_T$ , 25 GHz  $f_{MAX}$ ISOSAT<sup>TM</sup>-I silicon bipolar process. This process uses nitride self-alignment, submicrometer lithography, trench isolation, ion implantation, gold metallization and polyimide inter-metal dielectric and scratch protection to achieve excellent performance, uniformity and reliability.

#### **Typical Biasing Configuration and Functional Block Diagram**

#### **Differential Input/Differential Output**



C<sub>bypass</sub> = 1000 pF typical Good grounding of Pins 2, 3 is critical for proper operation and good VSWR performance of this part.

# $C_{block}$ $Input \bigcirc 1^{1} \qquad I_{8} \bigcirc V_{gc}$ $V_{ge} = 0 V$ $I \bigcirc 2^{1} \qquad I_{7} \bigcirc 0 \text{ output } +$ $C_{bypass} \bigcirc 4^{1} \qquad I_{5} \bigcirc 0 \text{ output } +$ $C_{bypass} \bigcirc V_{Cc} = 5 V$ =

Single Ended Input/Single Ended Output

 $^{*}$  Optional: For Single-Ended Output operation, Pin 7 may be left unterminated (no C  $_{block}$  or 50  $\Omega)$ 

Symbol	Parameter	Units	Absolute Maximum <sup>[1]</sup>
$V_{CC}$ - $V_{ee}$	Device Voltage	V	8
	Power Dissipation <sup>[2,3]</sup>	mW	600
	Input Power	dBm	+14
$V_{gc}$ - $V_{ee}$		V	7
$T_J$	Junction Temperature	°C	150
T <sub>STG</sub>	Storage Temperature	°C	-65 to 150

#### **IVA-05208 Absolute Maximum Ratings**

#### **Thermal Resistance**<sup>[2]</sup>: $\theta_{jc} = 150^{\circ}C/W$

#### Notes:

- 1. Permanent damage may occur is any of these limits are exceeded.
- 2.  $T_{CASE} = 25^{\circ}C$ . 3. Derate at 6.67 mW/°C for  $T_C > 60^{\circ}C$ .

## IVA-05208 Electrical Specifications<sup>[1]</sup>, $T_A = 25^{\circ}C$

Symbol	Parameters and Test Conditions: <sup>[2]</sup> $V_{CC} = 5 V$ , $V_{ee} = 0 V$ , $V_{gc} = 0 V$ , $Z_0 = 50 \Omega$		Units	Min.	Тур.	Max.
Gp	Power Gain $( S_{21} ^2)$	f = 0.5  GHz	dB	25	30	
$\Delta Gp$	Gain Flatness	f = 0.05 to 1.0 GHz	dB		± 0.8	
$f_{3dB}$	3 dB Bandwidth <sup>[3]</sup>		GHz	1.2	1.8	
GCR	Gain Control Range <sup>[4]</sup>	f = 0.5  GHz $V_{gc} = 0 \text{ to } 5 \text{ V}$	dB	25	30	
ISO	Reverse Isolation $( S_{21} ^2)$	f = 0.5  GHz $V_{gc} = 0 \text{ to } 5 \text{ V}$	dB		45	
VSWR	Input VSWR	f = 0.05  to  1.5  GHz $V_{gc} = 0 \text{ to } 5 \text{ V}$			2.0:1	
	Output VSWR	f = 0.05 to 1.5 GHz $V_{gc} = 0$ to 5 V			2.5:1	
NF	50 $\Omega$ Noise Figure	f = 0.5 GHz	dB		9	
P <sub>1dB</sub>	Output Power at 1 dB Gain Compression	f = 0.5 GHz	dBm		-3	
V <sub>OUT</sub>	Peak-to-Peak Single-Ended Output Voltage	f = 0.5 GHz	mVpp		450	
IP <sub>3</sub>	Output Third Order Intercept Point	nt $f = 0.5 \text{ GHz}$	dBm		7	
t <sub>D</sub>	Group Delay	f = 0.5 GHz	psec		400	
I <sub>CC</sub>	Supply Current		mA	25	35	50

#### Notes:

1. The recommended operating voltage range for this device is 4 to 6 V. Typical performance as a function of voltage is on the following page. 2. As measured using Input Pin 1 and Output Pin 6, with Output Pin 7 terminated into 50 ohms and Input Pin 4 at AC ground.

 Referenced from 50 MHz Gain.
The recommended gain control range for these devices for dynamic control is 0 to 4.2 V. Operation at gain control settings above 4.2V may result in gain increase rather than gain decrease.

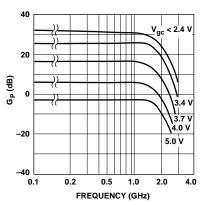




Figure 1. Typical Variable Gain vs. Frequency.

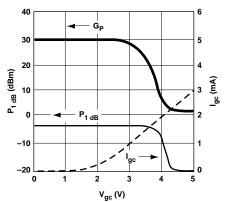


Figure 3. Power Gain and  $P_{1 dB}$  at 0.5 GHz and  $I_{gc}$  vs. Gain Control Voltage.

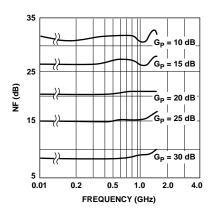


Figure 5. Noise Figure vs. Frequency.

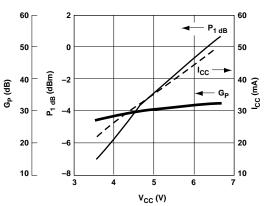


Figure 2. Power Gain and  $P_{1\ dB}$  at 0.5 GHz and  $I_{CC}$  vs. Bias Voltage with  $V_{gc}$  = 0 V.

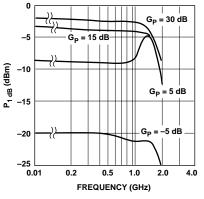


Figure 4. P<sub>1 dB</sub> vs. Frequency.

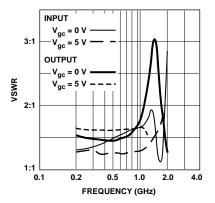
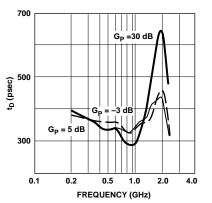


Figure 6. Input and Output VSWR vs. Frequency,  $V_{gc} = 0-5$  V.





#### **IVA-05208 Typical Performance,** continued, $T_A = 25^{\circ}C$ , $V_{CC} = 5 V$ , $V_{ee} = 0 V$

Figure 7. Group Delay vs. Frequency.

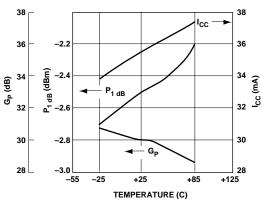
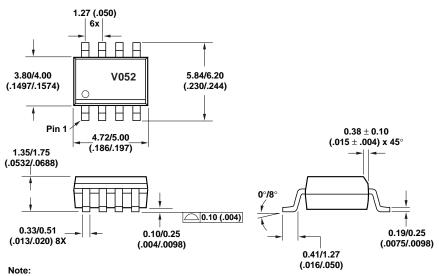


Figure 8. Power Gain and  $P_{1\ dB}$  at 0.5 GHz and  $I_{CC}$  vs. Case Temperature with  $V_{gc}$  = 0 V.

### **IVA-05208 Part Number Ordering Information**

Part Number	Number of Devices	Container		
IVA-05208-TR1	1,000	7" Reel		
IVA-05208-STR	10	Strip		

### **SO-8 Package Dimensions**



1. Dimensions are shown in millimeters (inches).

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